

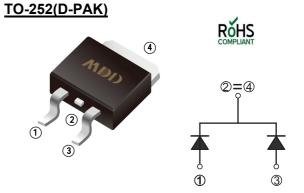
### MURD1020D THRU MURD1060D

Reverse Voltage -200 -600 Volts Forward Current - 10.0 Ampere

### **FAST RECOVERY EPI DIODES**

### **FEATURES**

- High frequency operation
- High surge forward current capability
- ◆ High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability



#### **MECHANICAL DATA**

**Case**: TO-252 molded plastic body **Terminals**: Plated axial leads, solderable per MIL-STD-750,

Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.0141 ounce(approx), 0.4 grams (approx)

#### PACKAGE SPECIFICATIONS

Package	Reel Size		Q'TY/Reel (pcs)	Box Size (mm)	QTY/Box (pcs)	Carton Size (mm)	Q'TY/Carton (pcs)	
TO-252	13'	330	2500	340×336×29	2500	353×346×365	25000	

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MCHARACTERISTICS	SYMBOL	MDD MURD1020D			UNITS	
Maximum repetitive peak reverse voltage	VRRM	200	200 400 600			
Maximum RMS voltage	VRMS	140	280	420	V	
Maximum DC blocking voltage	VDC	200	400	600	V	
Maximum average forward rectified current	l(AV)		А			
Peak forward surge current						
8.3ms single half sine-wave	IFSM			Α		
superimposed onrated load (JEDEC Method)						
Maximum instantaneous forward voltage at 5A	VF	1.0	1.3	1.6	V	
Maximum DC reverse current T <sub>A</sub> =25℃	,		uA			
at rated DC blocking voltage T <sub>A</sub> =125℃	lR					
Typical junction capacitance (NOTE 1)	Сл		pF			
Maximum Reverse Recovery Time	Trr		ns			
Typical thermal resistance (NOTE 2)	Reja		°C/W			
Operating junction and storage temperature range	ТЈ,Тѕтс		$^{\circ}$			

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0 V D.C.

- 2. Mounted on 10cm x 10cm x 1mm copper pad area
- 3. The typical data above is for reference only.

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# **Rating and Characteristic Curves**

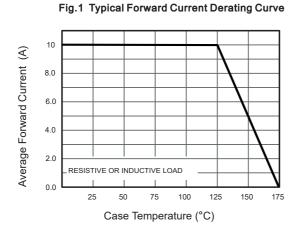


Fig.2 Typical Reverse Characteristics

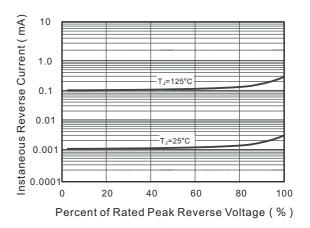


Fig.3 Typical Forward Characteristic

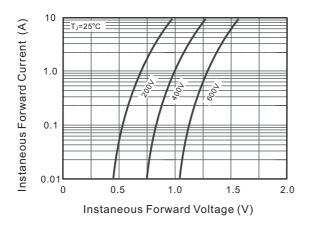
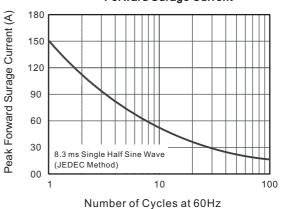


Fig.4 Maximum Non-Repetitive Peak Forward Surage Current



The curve above is for reference only.

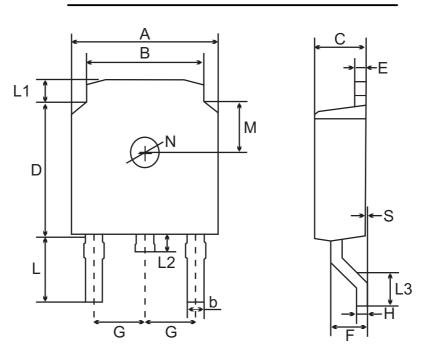


## **MURD1020D THRU MURD1060D**

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### **Outlitne Drawing**

### TO-252(D-PAK) Package Outline Dimensions



TO-252(D-PAK) mechanical data

U	NIT	Α	В	b	С	D	Е	F	G	Н	L	L1	L2	L3	S	М	Ν
mm	max	6.7	5.53	0.86	2.5	6.3	0.6	1.8	2.29 TYPICAL	0.60	3.4	1.2	1.0	1.75	0.15	1.98	1.3
mm	min	6.3	5.1	0.66	2.1	5.9	0.4	1.3		0.40	2.7	8.0	0.6	1.40	0.0	1.58	1.2

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